metrisis Film Metrology Specialists

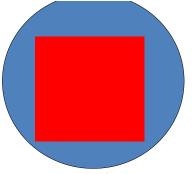
ThetaMetrisis APPLICATION NOTE #008

Film Thickness mapping by White Light Reflectance Spectroscopy (WLRS) and FR-Mapper

Goal: The characterization of film thickness uniformity over large areas.

Means & Methods: FR-Basic is combined with FR-Mapper for fast and accurate measurement of film thickness on pre-defined points over large areas. All measurements were performed with an FR-Basic tuned to operate in the 540-1000nm spectral regime while the sample was fixed on an FR-Mapper. The reflection probe had an active spot size of 0.5mm in diameter. The samples were 4inch Si wafers coated with SiO₂ (thermal or TEOS) and Si₃N₄ (LPCVD)/ SiO₂ (thermal). For the reference measurements, a highly reflective Al coated mirror (NT01-913-533, Edmund Optics) was used.

Results: In fig. 1 the scanned area (red) over the Si wafer (blue) is shown. Intentionally, the center of the 6x6cm² scanned area is shifted towards the bottom-left corner. In fig. 2a thickness values for TEOS SiO₂ are shown. Film thickness was measured in steps of 2mm in both axes (961 measurements in total). The mean thickness value was calculated to be 635.07nm with standard deviation of 4.24nm. Minimum thickness found to be 623.13nm and maximum thickness 641.35nm. In fig. 2b, the film thickness values for thermally grown SiO_2 (wet oxidation) for the same scanned area are shown. Thickness was measured in steps of 2mm in both axes (961 measurements in total). The mean thickness value was calculated to be 697.29nm with standard deviation of 0.93nm. Minimum thickness found to be 697.22nm and maximum thickness 701.32nm. Film thickness variation is certainly smaller in thermally grown SiO₂ and furthermore film thickness gradient presents a radial symmetry which is not the case for TEOS films. In fig. 3 film thickness values in a Si₃N₄/SiO₂ stack are illustrated.



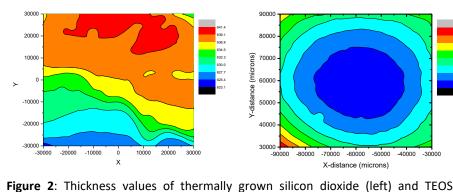
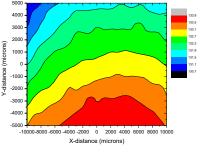
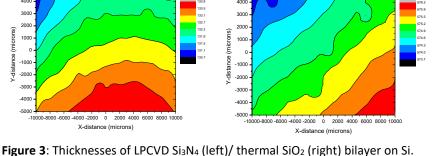


Figure 1: Layout of the area where the film thickness is measured.

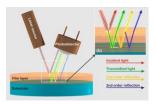




deposited (right)

Conclusions: FR-Mapper is connected to FR-Basic and is successfully in film thickness mapping of single and multi-layers.

-40000 -30000



For further information please contact us at info@thetametrisis.com or sales@thetametrisis.com ThetaMetrisis © 2012, www.thetametrisis.com